

## 0.5 dB LSB GaAs MMIC 5-BIT DIGITAL ATTENUATOR, 0.1 - 33 GHz

### Typical Applications

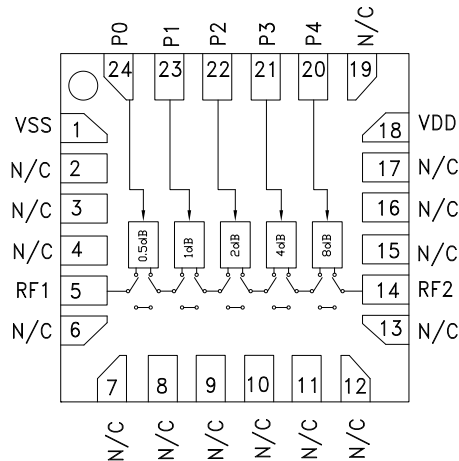
The HMC941ALP4E is ideal for:

- Fiber Optics & Broadband Telecom
- Microwave Radio & VSAT
- Military Radios, Radar & ECM
- Space Applications
- Sensors
- Test & Measurement Equipment

### Features

- 0.5 dB LSB Steps to 15.5 dB
- Single Positive Control Line Per Bit
- ±0.5 dB Typical Bit Error
- High Input IP3: +45 dBm
- 16mm<sup>2</sup> Leadless SMT Plastic Package

### Functional Diagram



### General Description

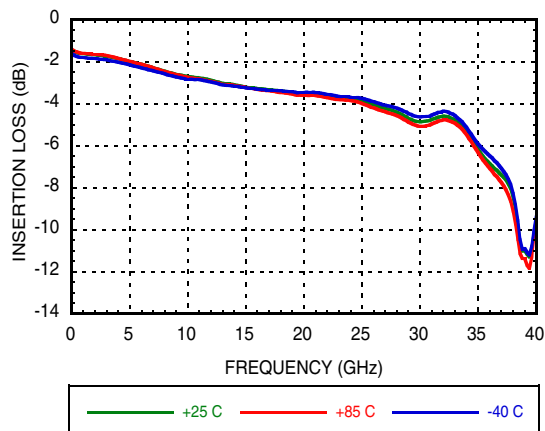
The HMC941ALP4E is a broadband 5-bit GaAs IC digital attenuators in low cost leadless surface mount packages. Covering 0.1 to 33.0 GHz, the insertion loss is less than 4 dB typical. The attenuator bit values are 0.5 (LSB), 1, 2, 4, 8, for a total attenuation of 15.5 dB. Attenuation accuracy is excellent at ±0.3 dB typical step error with an IIP3 of +45 dBm. Five control voltage inputs, toggled between +5V and 0V, are used to select each attenuation state.

### Electrical Specifications, $T_A = +25^\circ C$ , With $V_{dd} = +5V$ , $V_{ss} = -5V$ , $P_0 - P_4 = 0/ +5V$

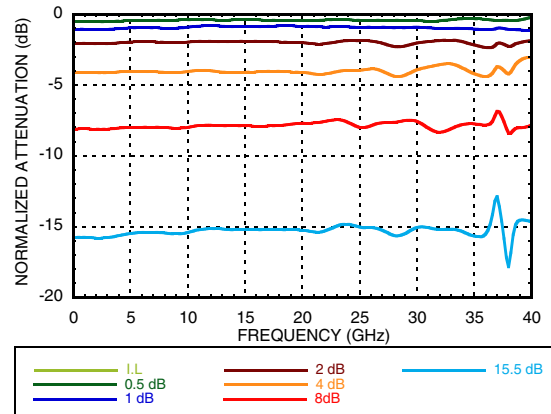
Parameter	Frequency (GHz)	Min.	Typ.	Max.	Units
Insertion Loss	0.1 - 18.0 GHz		3.5	4.5	dB
	18.0 - 26.5 GHz		4.0	6.0	dB
	26.5 - 33.0 GHz		5.0	6.5	dB
Attenuation Range	0.1 - 33.0 GHz		15.5		dB
Return Loss (RF1 & RF2, All Atten. States)	0.1 - 33.0 GHz		12		dB
Attenuation Accuracy: (Referenced to Insertion Loss)	0.5 - 7.5 dB States	0.1 - 33.0 GHz	± (0.3 + 4% of Atten. Setting) Max		dB
	8 - 15.5 dB States	0.1 - 33.0 GHz	± (0.3 + 8% of Atten. Setting) Max		dB
Input Power for 0.1 dB Compression	0.1 - 0.5 GHz		22		dBm
	0.5 - 33.0 GHz		26		dBm
Input Third Order Intercept Point (Two-Tone Input Power = +8 dBm Each Tone)	0.1 - 0.5 GHz		45		dBm
	0.5 - 33.0 GHz		42		dBm
Switching Characteristics	0.1 - 33.0 GHz	tRISE, tFALL (10/90% RF)	40		ns
		tON/tOFF (50% CTL to 10/90% RF)	50		ns
I <sub>dd</sub>	0.1 - 33.0 GHz	2.5	4.5	6.5	mA
I <sub>ss</sub>	0.1 - 33.0 GHz	-7.0	-6.0	-3.0	mA

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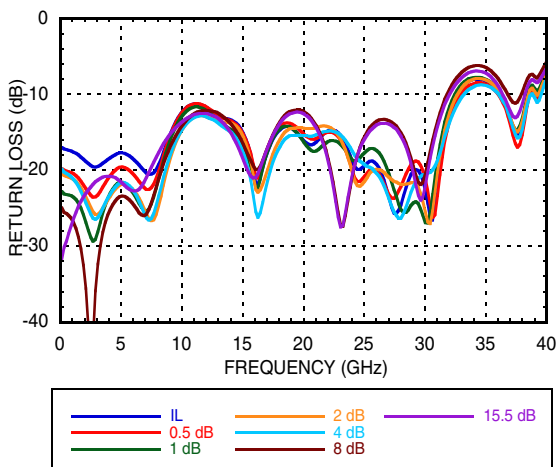
**Insertion Loss vs. Temperature**



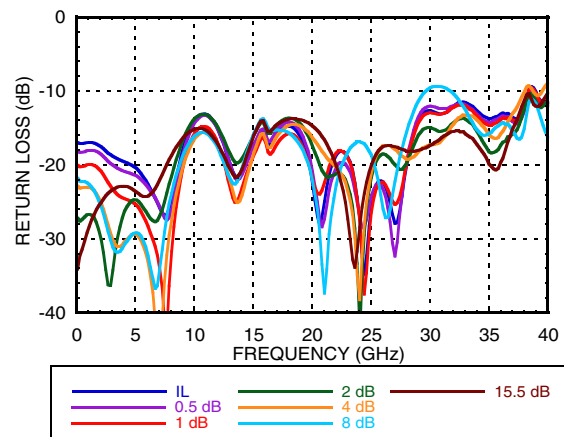
**Normalized Attenuation**  
(Only Major States are Shown)



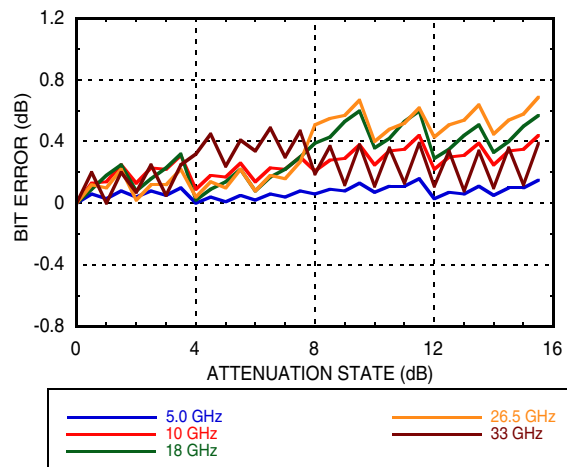
**Input Return Loss**  
(Only Major States are Shown)



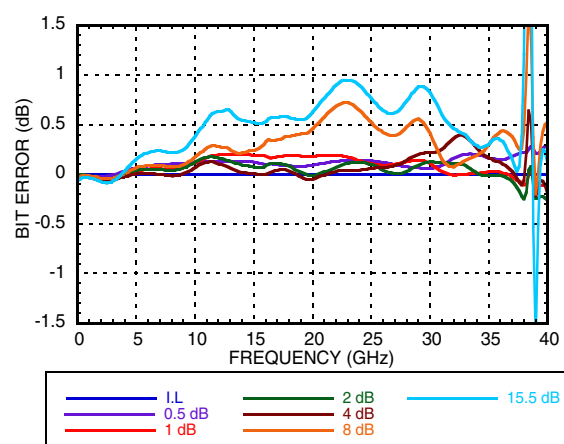
**Output Return Loss**  
(Only Major States are Shown)



**Bit Error vs. Attenuation State**

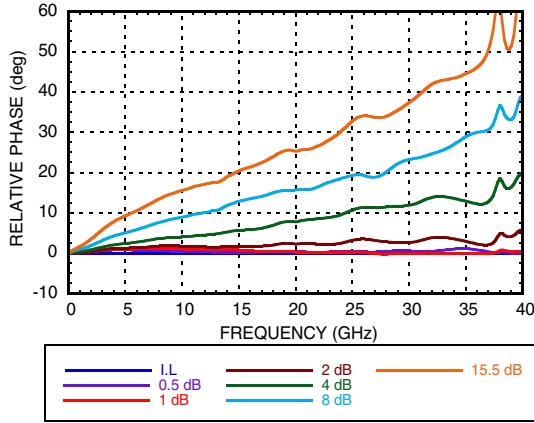


**Bit Error vs. Frequency**  
(Only Major States are Shown)

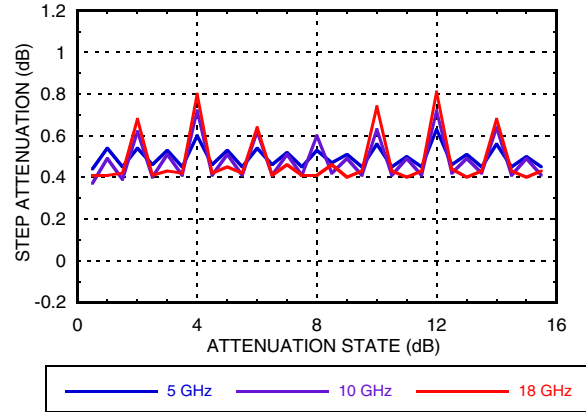


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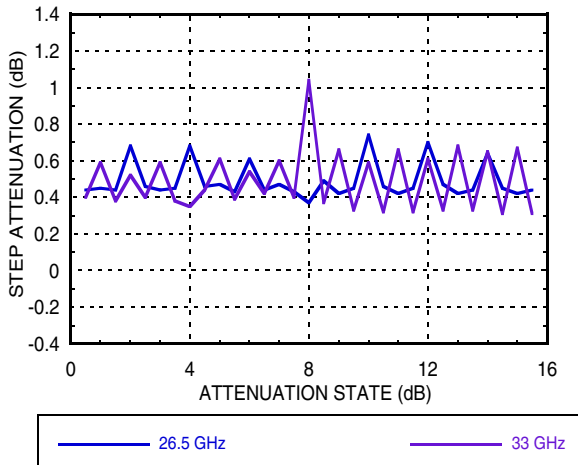
**Relative Phase vs. Frequency**  
(Only Major States are Shown)



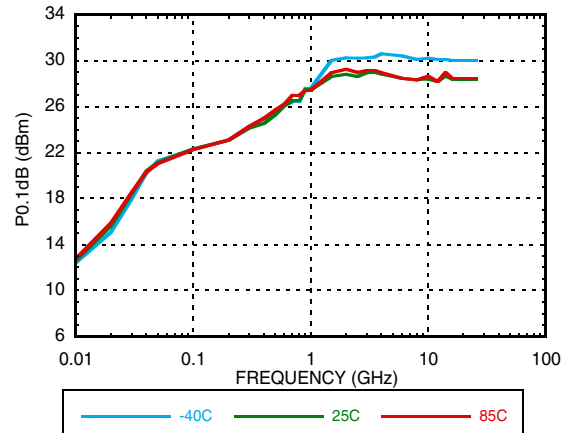
**Step Attenuation vs. Attenuation State**  
**0.1 - 18 GHz**



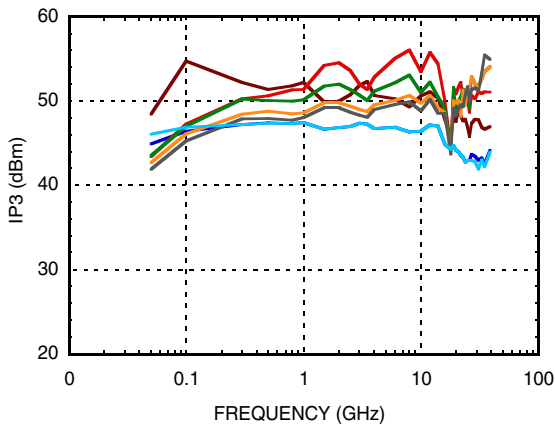
**Step Attenuation vs. Attenuation State**  
**18 - 33 GHz**



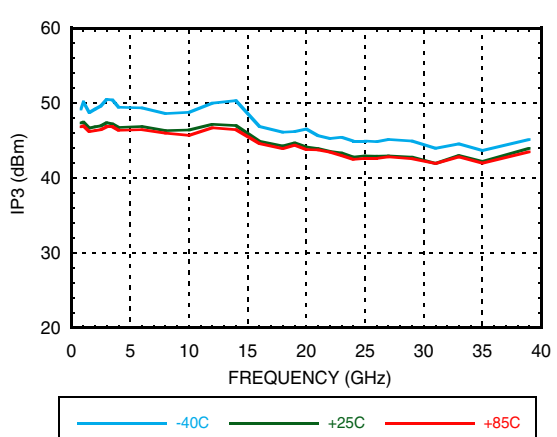
**Input Power for 0.1 dB Compression**



**Input IP3 Over Major Attenuation States**



**Input IP3 vs. Temperature**  
(Minimum Attenuation State)



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### Absolute Maximum Ratings

RF Input Power (0.1 to 33.0 GHz)	+27dBm
Control Voltage (P0 to P4)	Vdd+0.5
Vdd	+7 Vdc
Vss	-7 Vdc
Channel Temperature	150 °C
Continuous P <sub>diss</sub> (T = 85 °C) (derate 6.8 mW/°C above 85 °C)	0.453 W
Thermal Resistance	143.5 °C/W
Storage Temperature	-65 to 150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class1A

### Bias Voltages & Currents

Vdd	+5V @ 4.5 mA
Vss	-5V @ 6 mA

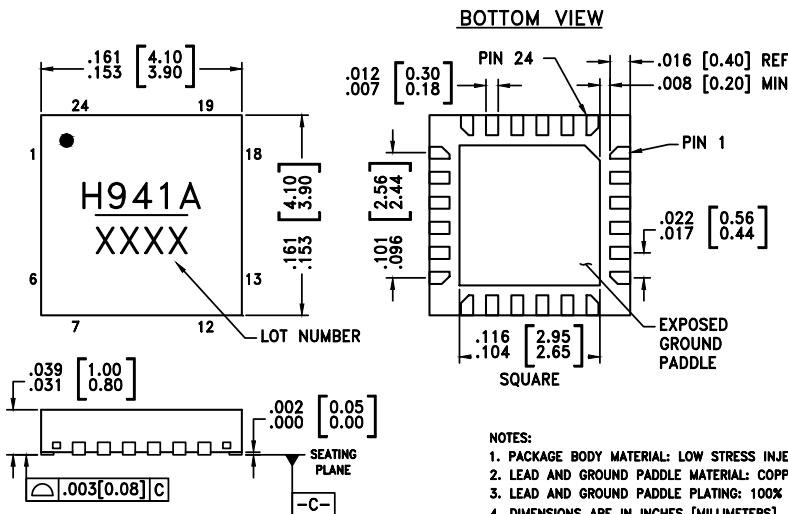
### Control Voltage

State	Bias Condition
Low	0 to 0.8V @ 1 μA (Typ)
High	2 to 5V @ 1 μA (Typ)



ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS

### Outline Drawing



### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[2]</sup>
HMC941ALP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL3 <sup>[1]</sup>	H941A XXXX

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX

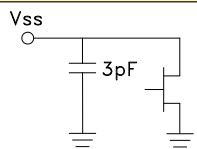
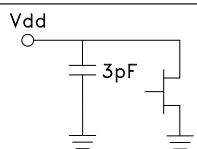
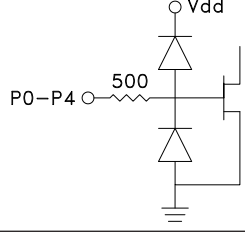
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### Truth Table

Control Voltage Input					Attenuation State RF1 - RF2
P4 8 dB	P3 4 dB	P2 2 dB	P1 1 dB	P0 0.5 dB	
High	High	High	High	High	Reference I.L.
High	High	High	High	Low	0.5 dB
High	High	High	Low	High	1 dB
High	High	Low	High	High	2 dB
High	Low	High	High	High	4 dB
Low	High	High	High	High	8 dB
Low	Low	Low	Low	Low	15.5 dB

Any Combination of the above states will provide an attenuation approximately equal to the sum of the bits selected.

### Pin Descriptions

Pad Number	Function	Description	Interface Schematic
1	Vss	Negative Bias -5V	
2-4, 6-13, 15-17, 19	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
5, 14	RF1, RF2	These pins are DC coupled and matched to 50 Ohm. Blocking capacitors are required if RF line potential is not equal to 0V.	
18	Vdd	Positive Bias +5V	
20 - 24	P0 - P4	See truth table and control voltage table.	
	GND	Package bottom must be connected to RF/DC ground.	